NSN 5961-01-086-6906

Diode Semiconductor Device - Page 1 of 1



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Overall Length:
2.100 inches
Mounting Facility Quantity:
1
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-9
Electrode Internally-electrically Connected To Case:
Anode
Mounting Method:
Threaded stud
Thread Size:
0.750 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
300.0 nonrepetitive peak reverse voltage and 200.0 repetitive peak reverse voltage and 140.0 reverse voltage, total rms
Current Rating Per Characteristic:
275.00 amperes forward current, average
Maximum Operating Tempurature Per Measurement Point:
190.0 degrees celsius junction
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 threaded stud and 1 uninsulated wire lead w/terminal lug
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig:
A110a0